TENTATIVE

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

HN9C10FT

VHF~UHF BAND LOW NOISE AMPLIFIER APPLICATIONS

TWO devices are built in to the super-thin and ultra super mini (6pins) package: TU6

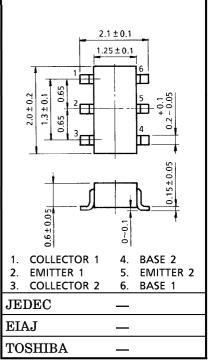
MOUNTED DEVICES

	Q1	Q2
Three-pins (SSM) mold products are corresponded.	2SC5261	2SC5086

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	Q1	Q2	UNIT
Collector-Base Voltage	V _{CBO}	15	20	V
Collector-Emitter Voltage	v_{CEO}	7	12	V
Emitter-Base Voltage	v_{EBO}	1.5	3	V
Collector Current	$I_{\mathbf{C}}$	15	80	mA
Base Current	I_{B}	7	40	mA
Collector Power Dissipation	PC	200		mW
Junction Temperature	T_{j}	15	°C	
Storage Temperature Range	$ m T_{stg}$	-55	°C	

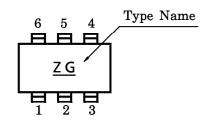
Unit in mm

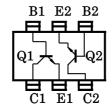


Weight: 0.008g

MARKING

PIN ASSIGNMENT (TOP VIEW)





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ELECTRICAL CHARACTERISTICS Q1 (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 10V, I_{E} = 0$	_	_	1	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=1V, I_{C}=0$			1	μ A
DC Current Gain	${ m h_{FE}}$	$V_{CE}=5V$, $I_{C}=7mA$	50	_	160	_
Transition Frequency	$\mathbf{f_{T}}$	$V_{CE}=5V$, $I_{C}=7mA$	9	12	_	GHz
Insertion Gain	$ S_{21e} ^2$ (1)	$V_{CE} = 5V, I_{C} = 7mA, f = 1000MHz$	_	13.5	_	dB
	$ S_{21e} ^2$ (2)	$V_{CE} = 5V, I_{C} = 7mA, f = 2000MHz$	5	7.5	_	dB
Noise Figure	NF (1)	$V_{CE} = 5V, I_{C} = 3mA, f = 1000MHz$	_	1.4	_	dB
	NF (2)	$V_{CE}=5V$, $I_{C}=3mA$, $f=2000MHz$	_	1.7	3	dB

ELECTRICAL CHARACTERISTICS Q2 (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	ICBO	$V_{CB} = 10V, I_{E} = 0$	_	_	1	μ A
Emitter Cut-off Current	I_{EBO}	$V_{EB}=1V, I_C=0$		_	1	μ A
DC Current Gain	$h_{ extbf{FE}}$	$V_{CE} = 10V$, $I_{C} = 20mA$	80		240	_
Transition Frequency	$ m f_{T}$	$V_{CE} = 10, I_{C} = 20 \text{mA}$	5	7	_	GHz
Insertion Gain	$ S_{21e} ^2$ (1)	$V_{\text{CE}} = 10\text{V}, I_{\text{C}} = 20\text{mA}, \\ f = 500\text{MHz}$	_	16.5	_	dB
	$ S_{21e} ^2$ (2)	$V_{\text{CE}} = 10V, I_{\text{C}} = 20\text{mA}, \\ f = 1000\text{MHz}$	8	11	_	dB
Noise Figure	NF (1)	$V_{CE} = 10V, I_{C} = 5mA, f = 500MHz$		1	_	dB
	NF (2)	$V_{CE} = 10V, I_{C} = 5mA, f = 1000MHz$	_	1.1	2	dB

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